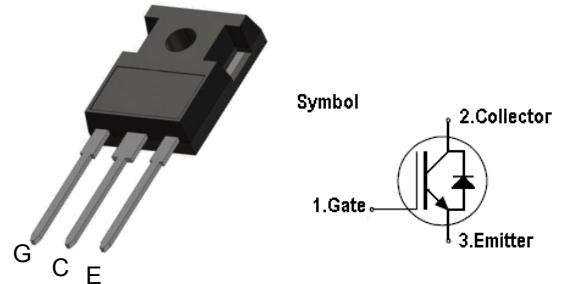


## IGBT in TO-247

### Features

- 1200V 20A,  $V_{CE(sat)(typ.)} = 2.05 V@20A$
- High speed switching
- Higher system efficiency
- Soft current turn-off waveforms
- Square RBSOA



### Mechanical Data

- **Case:** TO-247 (plastic package).  
Lead free; RoHS compliant
- **Molding Compound Flammability Rating:**  
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:  
260 °C/10 sec. at terminals

### Benefits

- High Efficiency for Motor Control
- Rugged Performance
- Excellent Current Sharing in Parallel Operation

### Applications

CREATEK's IGBTs offer lower losses and higher energy for application such as motor drive ,UPS, inverter and other soft switching applications.

### Absolute Maximum Ratings

Symbol	Parameter	Value	Units
$V_{CES}$	Collector-Emitter Voltage	1200	V
$V_{GES}$	Gate-Emitter Voltage	30	V
$I_C$	Continuous Collector Current ( $T_C=25^\circ C$ )	40	A
	Continuous Collector Current ( $T_C=100^\circ C$ )	20	A
$I_{CM}$	Pulsed Collector Current (Note 1)	80	A
$I_F$	Diode Continuous Forward Current ( $T_C=100^\circ C$ )	15	A
$I_{FM}$	Diode Maximum Forward Current (Note 1)	80	A
$t_{sc}$	Short Circuit Withstand Time	10	us
$t_{sc (Max)}$	Maximum Short Circuit Withstand Time	>23	us
$I_{sc}$	Short Circuit Current	140	A
$P_D$	Maximum Power Dissipation ( $T_C=25^\circ C$ )	190	W
	Maximum Power Dissipation ( $T_C=100^\circ C$ )	75	W
$T_J$	Operating Junction Temperature Range	-55 to +150	°C
$T_{STG}$	Storage Temperature Range	-55 to +150	°C

### Thermal Characteristics

Symbol	Parameter	Max.	Units
$R_{th j-c}$	Thermal Resistance, Junction to case for IGBT	0.45	°C/ W
$R_{th j-c}$	Thermal Resistance, Junction to case for Diode	0.85	°C/W
$R_{th j-a}$	Thermal Resistance, Junction to Ambient	40	°C/W

## Electrical Characteristics (TC=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$BV_{CES}$	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	1200	-	-	V
$I_{CES}$	Collector-Emitter Leakage Current	$V_{CE} = 1200V, V_{GE} = 0V$	-	-	250	$\mu A$
$I_{GES}$	Gate Leakage Current, Forward	$V_{GE} = 30V, V_{CE} = 0V$	-	-	100	nA
	Gate Leakage Current, Reverse	$V_{GE} = -30V, V_{CE} = 0V$	-	-	-100	nA
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 250\mu A$	4.5	5.0	5.5	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{GE} = 15V, I_C = 20A$	-	2.1	2.3	V
$Q_g$	Total Gate Charge	$V_{CC} = 960V$ $V_{GE} = 15V$ $I_C = 15A$	-	195	-	nC
$Q_{ge}$	Gate-Emitter Charge		-	90	-	nC
$Q_{gc}$	Gate-Collector Charge		-	105	-	nC
$t_{d(on)}$	Turn-on Delay Time		-	21	-	ns
$t_r$	Turn-on Rise Time	$V_{CC} = 600V$ $V_{GE} = 15V$ $I_C = 20A$ $R_G = 10\Omega$ Inductive Load $T_C = 25^\circ C$	-	32	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	280	-	ns
$t_f$	Turn-off Fall Time		-	220	-	ns
$E_{on}$	Turn-on Switching Loss		-	1.05	-	mJ
$E_{off}$	Turn-off Switching Loss		-	1.7	-	mJ
$E_{ts}$	Total Switching Loss		-	2.75	-	mJ
$C_{ies}$	Input Capacitance		$V_{CE} = 25V$ $V_{GE} = 0V$ $f = 100kHz$	-	1080	-
$C_{oes}$	Output Capacitance	-		175	-	pF
$C_{res}$	Reverse Transfer Capacitance	-		120	-	pF
$R_{Gint}$	Integrated gate resistor	$f = 1M; V_{pp} = 1V$	-	8.8	-	$\Omega$

## Electrical Characteristics of Diode (TC=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_F$	Diode Forward Voltage	$I_F = 15A$	-	2.1	2.3	V
$t_{rr}$	Diode Reverse Recovery Time	$V_{CE} = 600V$ $I_F = 15A$ $di/dt = 500A/\mu s$	-	110	-	ns
$I_{rr}$	Diode peak Reverse Recovery Current		-	15	-	A
$Q_{rr}$	Diode Reverse Recovery Charge		-	1050	-	nC

### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature

**Typical Characteristics**

Fig 1. maximum DC collector current VS. case temprature

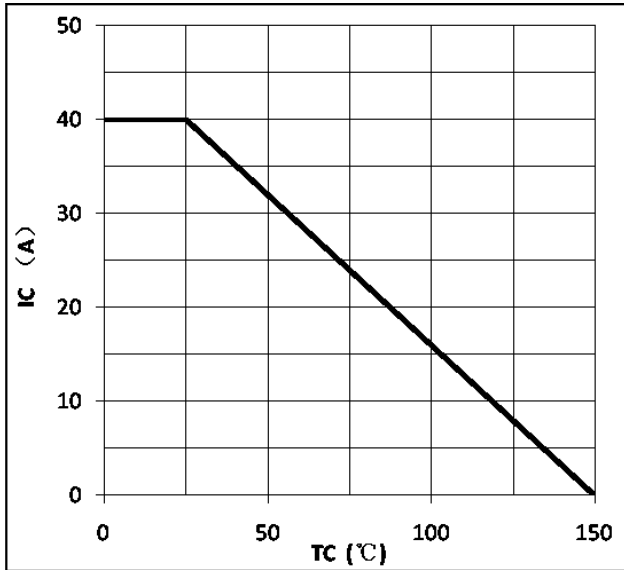


Fig 2. power dissipation VS. case temprature

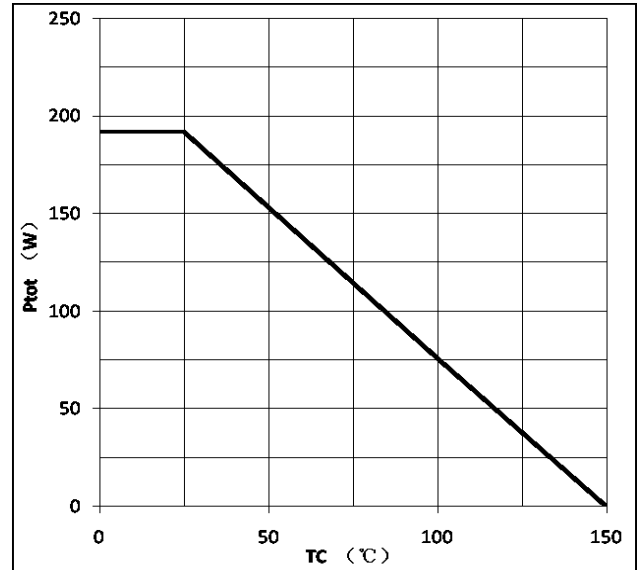


Fig 3. Forward SOA, TC=25°C, TJ≤150°C

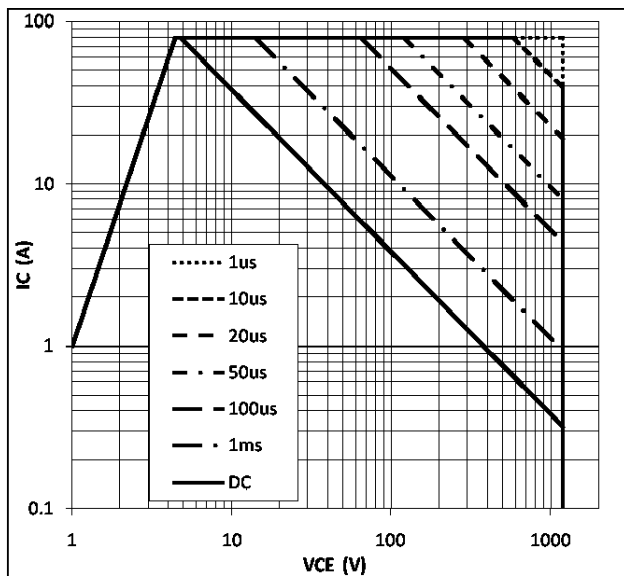
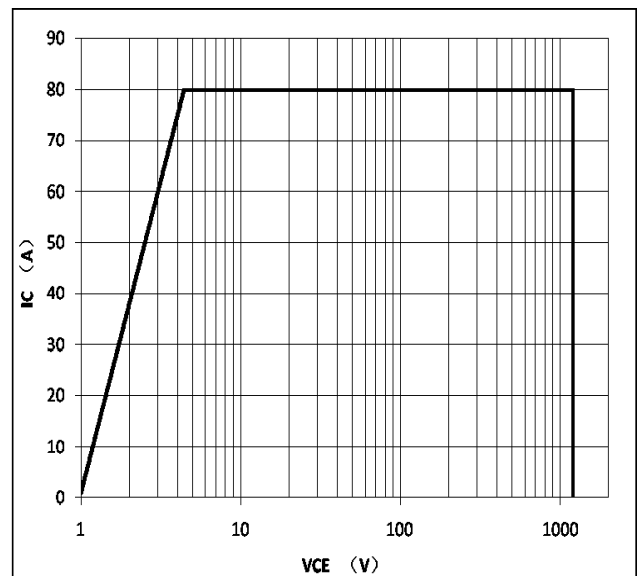


Fig 4. Reverse bias SOA, TJ=150°C, VGE=15V



**Typical Characteristics**

Fig 5. Typical IGBT output characteristic ( $T_j=25^\circ\text{C}$ )

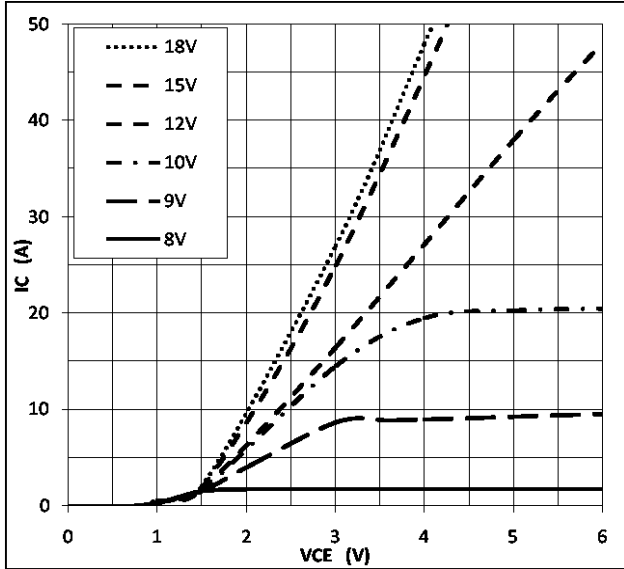


Fig 6. Typical trans characteristics,  $V_{CE}=20\text{V}$ ,  $t_p=20\mu\text{s}$

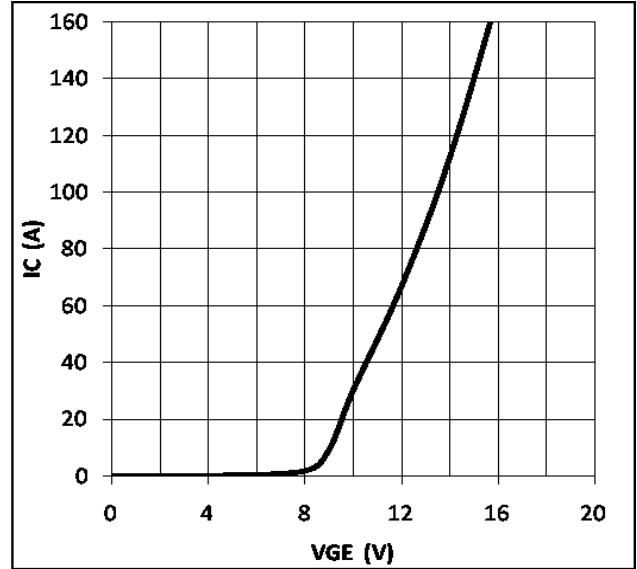


Fig 7. Typical diode forward characteristic,  $t_p=300\mu\text{s}$

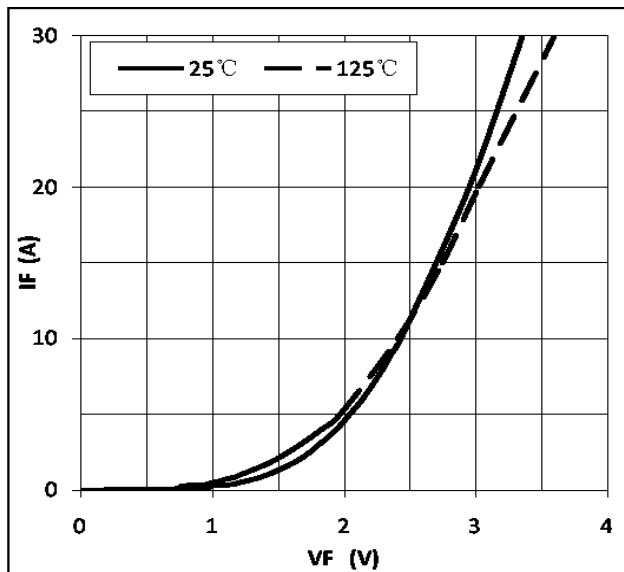
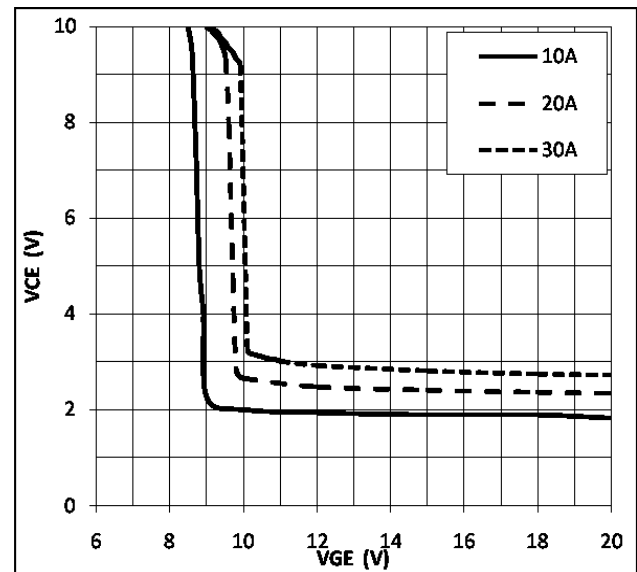


Fig 8. Typical  $V_{CE}$  VS.  $V_{GE}$ ,  $T_J=25^\circ\text{C}$



**Typical Characteristics**

Fig 9. Typical VCE VS. VGE,  $T_J=125^\circ\text{C}$

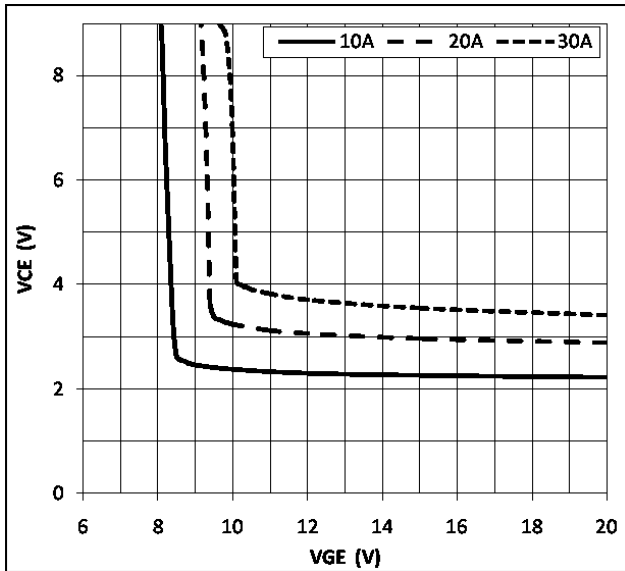


Fig 10. Typical energy loss VS. IC  $T_C=25^\circ\text{C}$ ,  $L=500\mu\text{H}$ ,  $V_{CE}=600\text{V}$ ,  $V_{GE}=15\text{V}$ ,  $R_g=28\Omega$

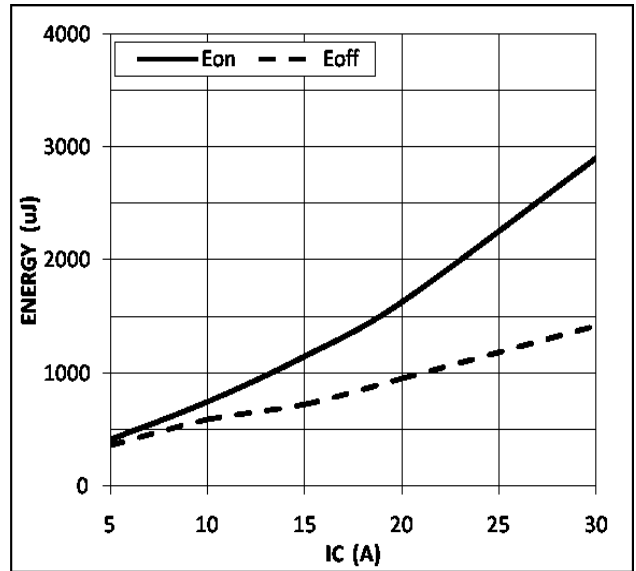


Fig 11. Typical switching time VS. IC,  $T_C=25^\circ\text{C}$ ,  $L=500\mu\text{H}$ ,  $V_{CE}=600\text{V}$ ,  $V_{GE}=15\text{V}$ ,  $R_g=28\Omega$

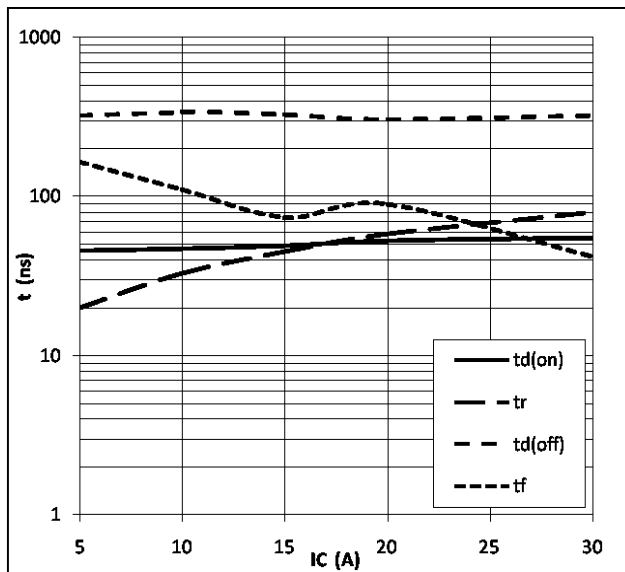
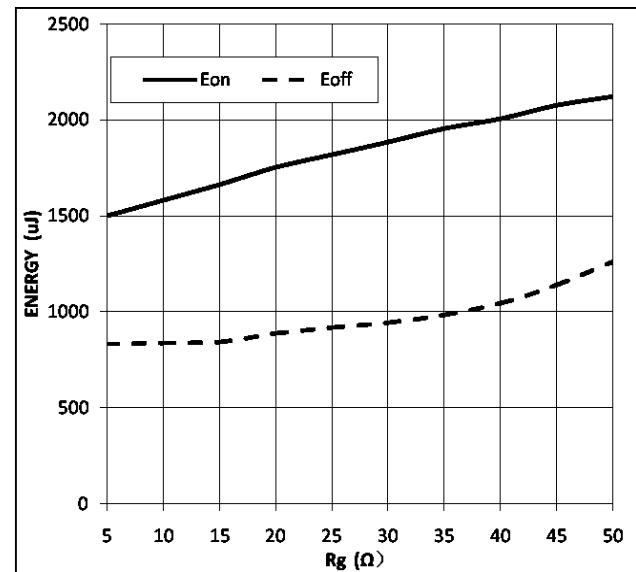


Fig 12. Typical energy loss VS. Rg,  $T_C=25^\circ\text{C}$ ,  $L=500\mu\text{H}$ ,  $V_{CE}=600\text{V}$ ,  $V_{GE}=15\text{V}$ ,  $I_C=20\text{A}$



**Typical Characteristics**

Fig 13. Typical switching time VS.  $R_g$ ,  $T_C=25^{\circ}C$ ,  
 $L=500\mu H, V_{CE}=600V, V_{GE}=15V, I_C=20A$

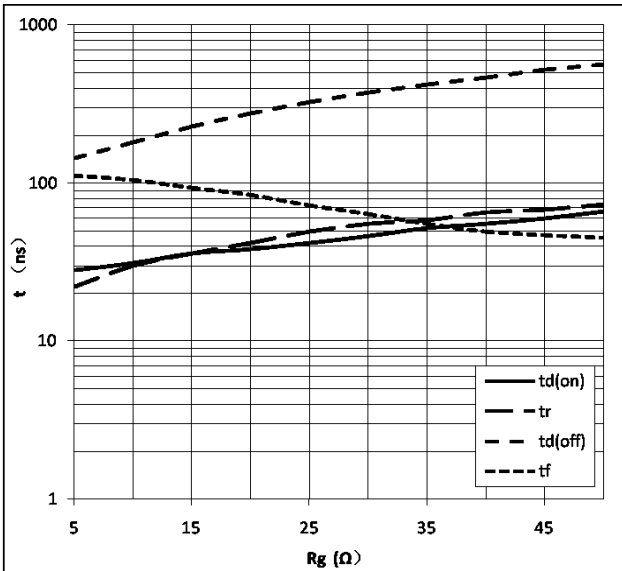


Fig 14. Typical diode  $I_{rrm}$  VS.  $I_F$ ,  $T_C=25^{\circ}C$   
 $V_{CC}=600V, V_{GE}=15V$

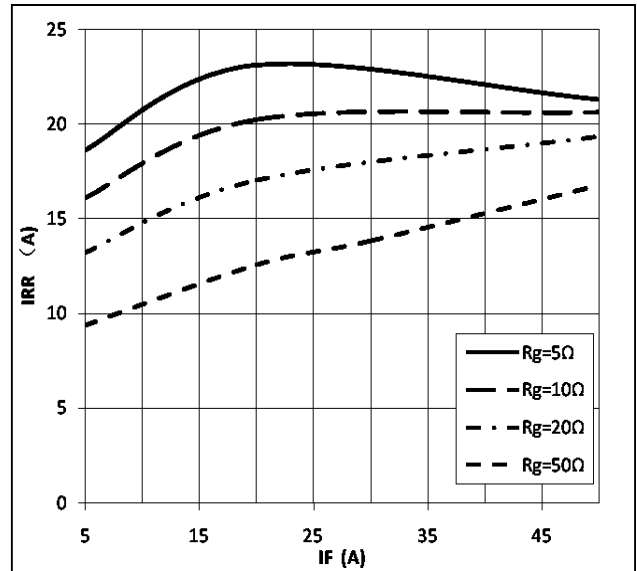


Fig 15. Typical diode  $I_{rrm}$  VS.  $dI_F/dt$   
 $V_{CC}=600V, V_{GE}=15V, I_F=20A$

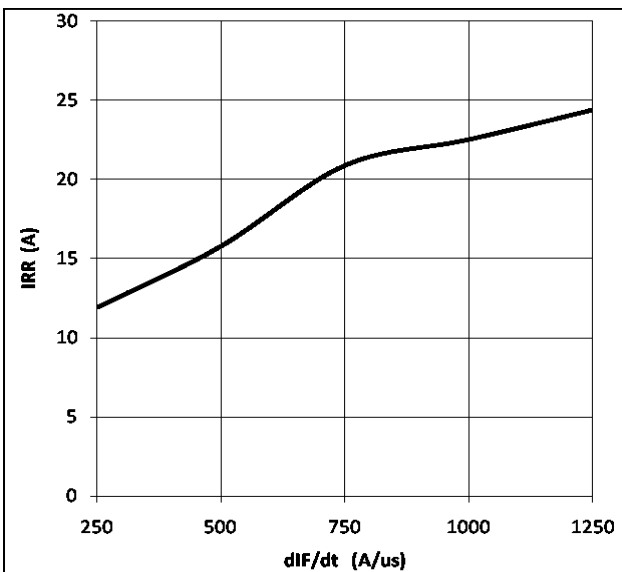
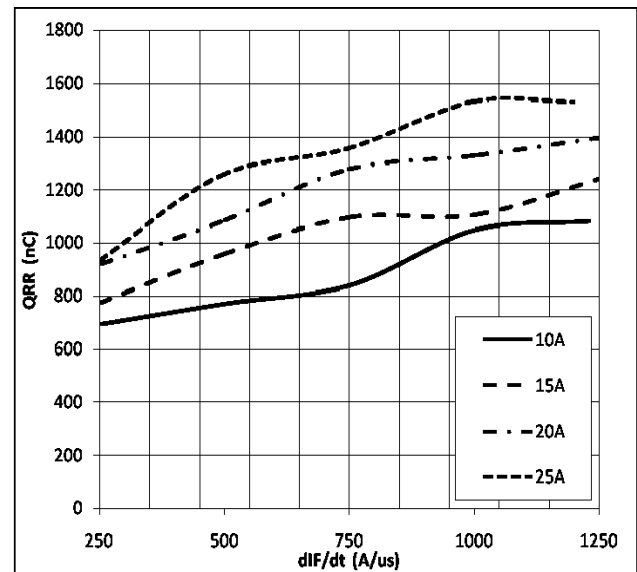


Fig 16. Typical diode QRR VS.  $dI_F/dt$   
 $V_{CC}=600V, V_{GE}=15V$



**Typical Characteristics**

Fig 17. Typical capacitance VS. VCE, VGE=0V, f=100kHz

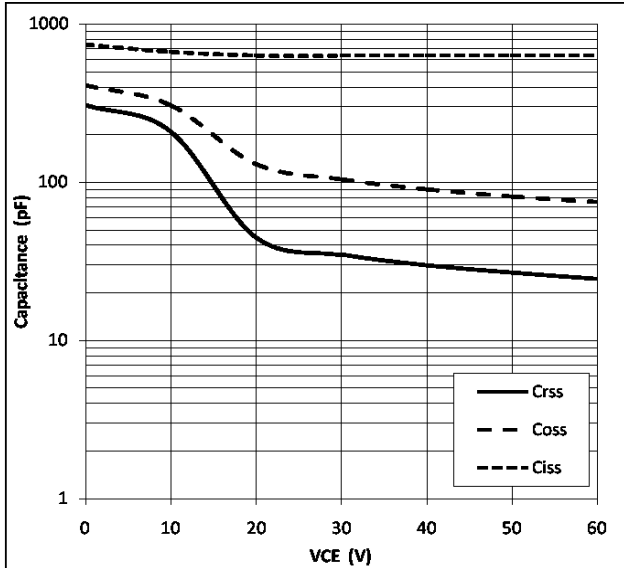


Fig 18. Typical gate charge VS. VGE, IC=20A

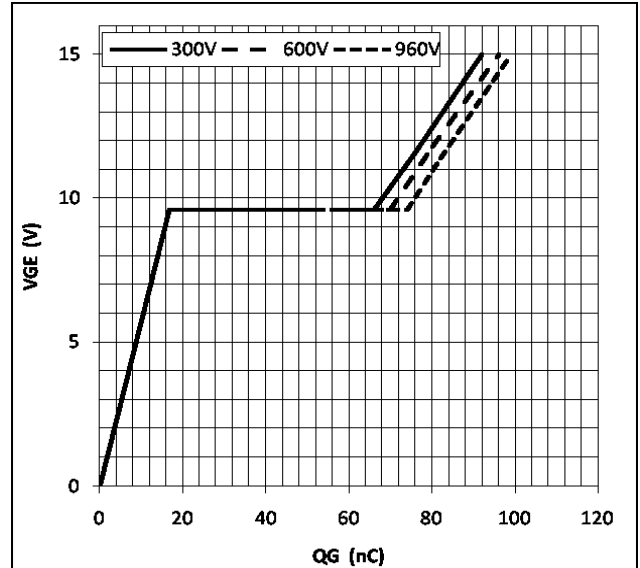
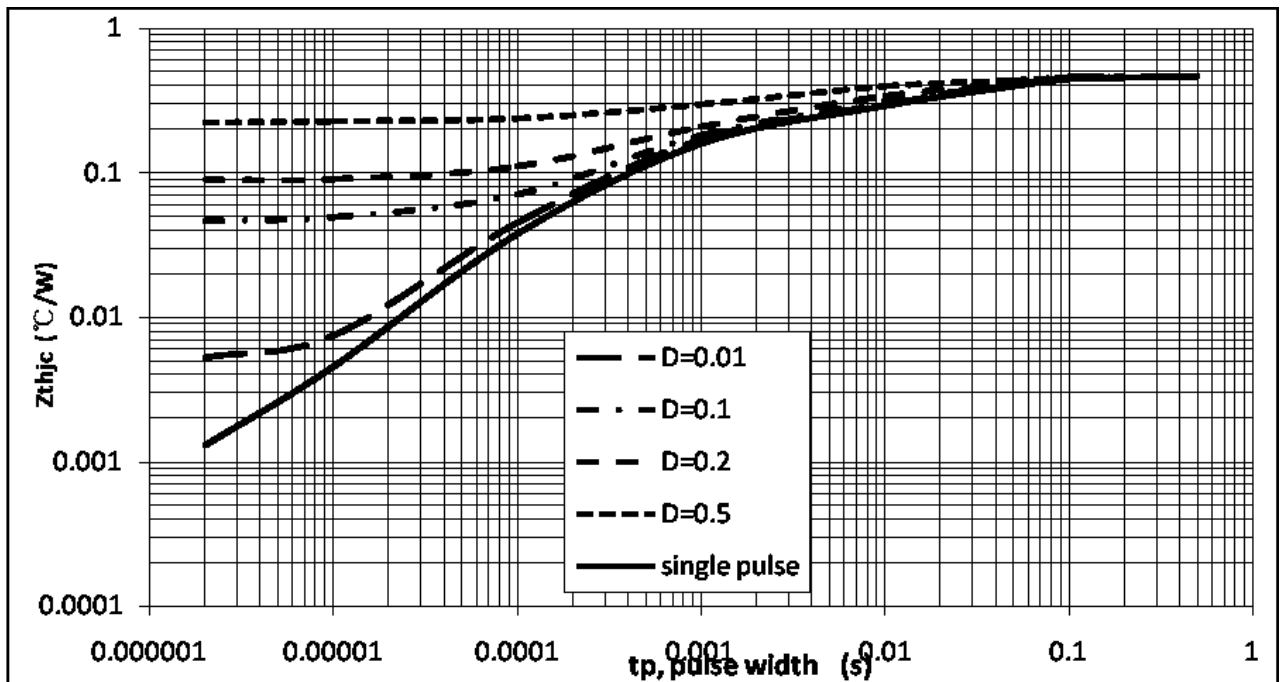
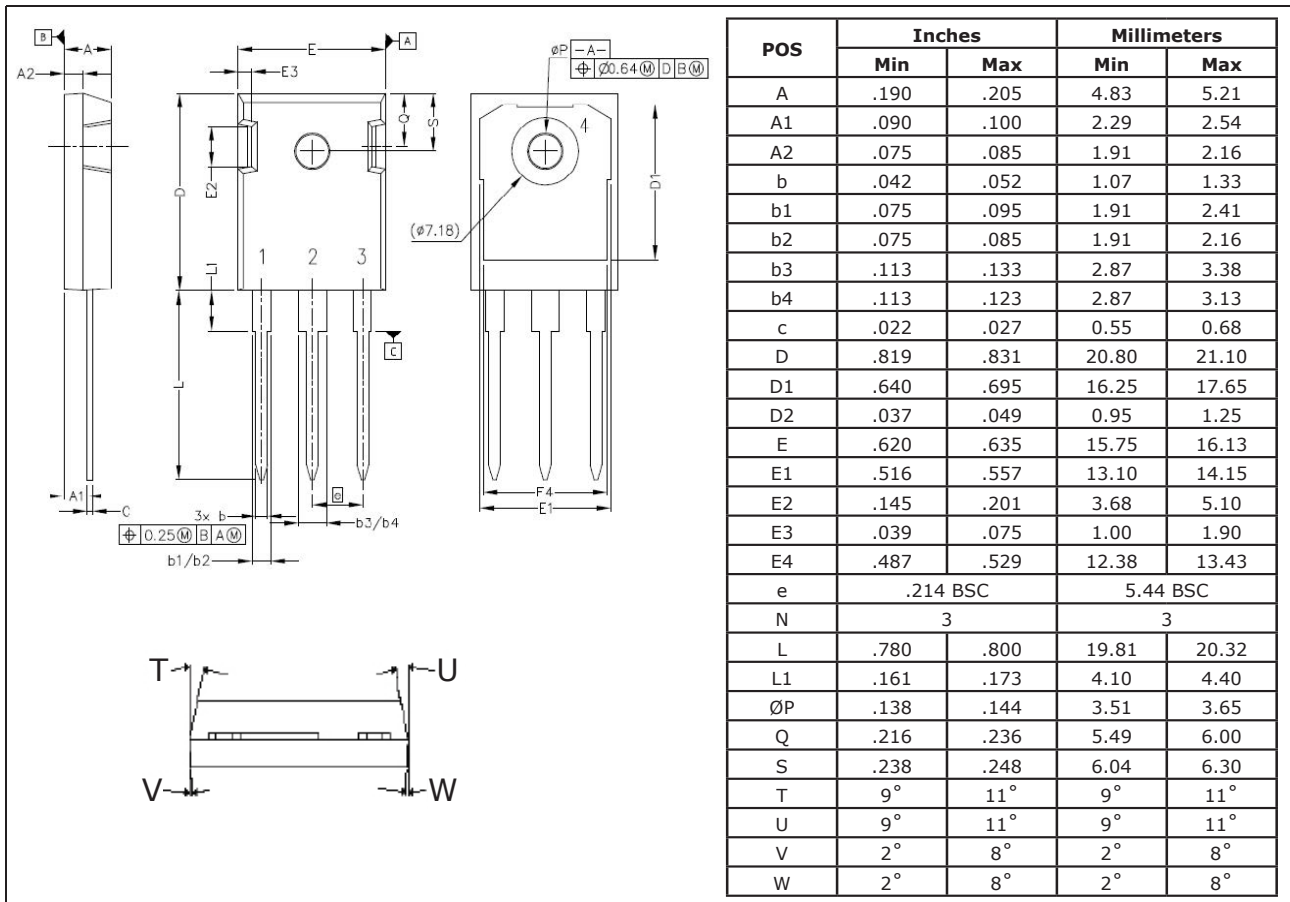


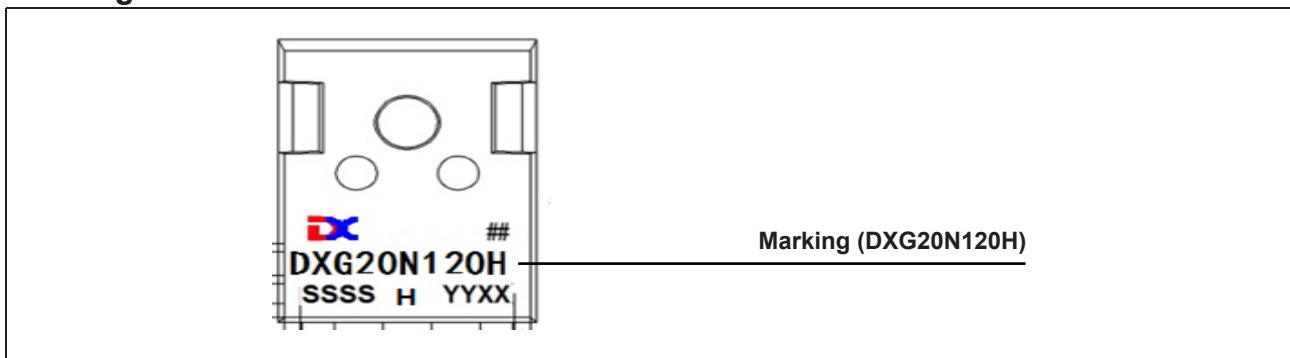
Fig 19. Normalized transient thermal impedance, junction-to-case  
Note1: Duty factor  $D=t1/t2$ ; Note2: peak  $TJ=PDM \times Zthjc + TC$



## Package Dimensions



## Marking



## Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
CXG20N120H	TO-247	Tube/BOX	2000pcs / BOX	EIA STD RS-481

## Revision history

Date	Revision	Changes
23-May-2012	1.0	Initial release
11-Nov.-2019	1.1	Add Marking



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